


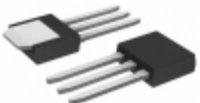




	<h2 style="color: red;">NTD6416ANLT4G</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">NTD6416ANLT4G</a></p> <p><b>Hersteller / Marke:</b> <a href="#">AMI Semiconductor / ON Semiconductor</a></p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 100V 19A DPAK</p> <p><b>Datenblätter:</b>  <a href="#">NTD6416ANLT4G.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 119184 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">NTD6416ANLT4G</a>
Hersteller	<a href="#">AMI Semiconductor / ON Semiconductor</a>
Beschreibung	MOSFET N-CH 100V 19A DPAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	119184 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	71W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	19A (Tc)
Rds On (Max) @ Id, Vgs	74 mOhm @ 19A, 10V
VGS (th) (Max) @ Id	2.2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	40nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1000pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)



















































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Sie können auch interessiert sein:

 <p><b>NTD6416ANG</b> ON NTD6416ANG ON</p>	 <p><b>NTD65N03R-001</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 9.5A IPAK</p>	 <p><b>NTD65N03R-035</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 9.5A IPAK</p>	 <p><b>NTD6416ANT4G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 17A DPAK</p>
 <p><b>NTD6416AN-1G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 17A IPAK</p>	 <p><b>NTD6416ANL-1G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 19A IPAK</p>	 <p><b>NTD6416ANL4G</b> ON ON TO252</p>	 <p><b>NTD65N03R</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 9.5A DPAK</p>

### heiße Teile

Mehr

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